PATENT COOPERATION TREATY

PCT

Translation INTERNATIONAL PRELIMINARY REPORT ON PATENTABILITY

(Chapter II of the Patent Cooperation Treaty)

(PCT Article 36 and Rule 70)

Applicant's or a	agent's file reference	FOR FURTHER AC	CTION	See Form PCT/IPEA/416			
nternational a	oplication No.	International filing dat	e (day/month/year)	Priority date (day/month/year)			
PCT/RU	2004/000006	14.01.2004	1	13.01.2003			
nternational P	atent Classification (IPC)	or national classification and I	PC	1			
H01L21	/324						
Applicant				-			
INSTI	TUT FIZIKI			NNOGO INSTITUTA FIZIKI			
		POLUPR	OVODNIKOV				
		al preliminary examination rep		International Preliminary Examining Authority			
2. This	REPORT consists of a to	tal of3	sheets, includin	ng this cover sheet.			
3. This	report is also accompanie	ed by ANNEXES, comprising:					
a. [(sent to the application)	ant and to the International Bu	reau) a total of	sheets, as follows:			
	sheets of the	description, claims and/or draw	wings which have been	amended and are the basis for this report and/or			
	sheets contai Instructions)	ning rectifications authorized b	by this Authority (see Ru	ule 70.16 and Section 607 of the Administrative			
				nsiders contain an amendment that goes beyond			
	the disclosur Box.	e in the international applicati	on as filed, as indicated	d in item 4 of Box No. I and the Supplemental			
ь. Г		ational Bureau only) a total of ((indicate type and numb	er of electronic carrier(s))			
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	related thereto, in co	omputer readable form only, as	s indicated in the Suppl	, containing a sequence listing and/or tables emental Box Relating to Sequence Listing (see			
		dministrative Instructions).	FF				
4. This	report contains indication	ns relating to the following iten	ns:				
\boxtimes	Box No. I Bas	is of the report					
	Box No. II Pric	rity					
	Box No. III Nor	-establishment of opinion with	regard to novelty, inver	ntive step and industrial applicability			
\Box		k of unity of invention	, <u>.</u>				
		•	35(2) with regard to nov	elty, inventive step or industrial applicability;			
لحا		tions and explanations supporti		,			
	Box No. VI Cer	tain documents cited					
	Box No. VII Certain defects in the international application						
	Box No. VIII Certain observations on the international application						
Date of subm	ission of the demand		Date of completion of t	his report			
			-	•			
Name and mailing address of the IPEA/RU			Authorized officer				
Facsimile No		I	Telephone No.				

INTERNATIONAL PRELIMINARY REPORT ON PATENTABILITY

International application No.
PCT/RU2004/00006

Box	No. I	Basis of the report						
1.	With	egard to the language, this report is based on the international application in the language in which it was filed, unless otherwise ted under this item.						
		This report is based on translations from the original language into the following language which is the language of a translation furnished for the purposes of:						
		international search (Rule 12.3 and 23.1(b))						
		publication of the international application (Rule 12.4)						
	****	international preliminary examination (Rule 55.2 and/or 55.3)						
2.	recei	regard to the elements of the international application, this report is based on <i>(replacement sheets which have been furnished to the</i> ing Office in response to an invitation under Article 14 are referred to in this report as "originally filed" and are not annexed to						
	this r	eport):						
		the international application as originally filed/furnished the description:						
		pages as originally filed/furnished as originally filed/furnished as originally filed/furnished						
		magazit						
	\Box	the claims:						
		nos. as originally filed/furnished						
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	ш	the drawings: sheets as originally filed/furnished						
		1 control by this radiotity on						
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		a sequence listing and/or any related table(s) – see Supplemental Box Relating to Sequence Listing.						
3.	Ш	The amendments have resulted in the cancellation of:						
		the description, pages						
		the claims, nos.						
		the drawings, sheets/figs						
		the sequence listing (specify): any table(s) related to sequence listing (specify):						
4.	\Box	any table(s) related to sequence listing (specify): This report has been established as if (some of) the amendments annexed to this report and listed below had not been made, since						
"	لــا	they have been considered to go beyond the disclosure as filed, as indicated in the Supplemental Box (Rule 70.2(c)).						
		the description, pages						
		the claims, nos.						
		the drawings, sheets/figs						
		the sequence listing (specify):						
	any table(s) related to sequence listing (specify):							
*	* If item 4 applies, some or all of those sheets may be marked "superseded."							

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Box		Reasoned statement under Article 35(2) with regard to novelty, inventive step or industrial applicability; citations and explanations supporting such statement		
1.	Statement			
	Novelty (N)	Claims	1-9	YES
		Claims		NO
	Inventive step (IS)		1-9	YES
i		Claims		NO
	Industrial applicability (IA)	Claims	1-9	YES
		Claims		NO
l				

2. Citations and explanations (Rule 70.7)

This report makes reference to the following documents cited in the search report:

D1: RU 2164719 C1 D2: DE 19753494 A1
D3: US 6323109 B1 D4: US 6306730 B2.

A method for producing a silicon on insulator structure is claimed in claim 1 and independent claims 2-9.

Each of the documents D2-D4 discloses a method for producing silicon on insulator structures wherein hydrogen ions are implanted on a silicon wafer, and the silicon wafer and the substrate are joined, bonded, and delaminated on the implanted layer.

The prior art closest to the method disclosed in claim 1 is the method for producing silicon on insulator structures according to D1, wherein, in addition to the features mentioned above, after the hydrogen ions are implanted on the wafer, the silicon wafer and substrate are chemically treated.

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Box No. V Reasoned statement under Article 35(2) with regard to novelty, inventive step or industrial applicability; citations and explanations supporting such statement

Neither D1 nor D2-D4, however, discloses the features of claim 1 that after chemical treatment, drying takes place, physically adsorbed substances are removed from the surface of the wafer and the substrate, the wafer and substrate are joined, they are bonded and delaminated on the implanted layer of the wafer in one stage, at a low vacuum pressure, and at a temperature at which hydrogen introduced during implantation remains in the silicon in the bound state.

The above-mentioned distinguishing features, which serve to improve the quality of silicon on insulator structures owing to the reduced concentration of defects and the virtually total absence of bubbles on the surface of the structures and in the silicon film, are not obvious.

Consequently, claim 1 and dependent claims 2-9 meet the requirements of novelty and inventive step. Claims 1-9 meet the requirement of industrial applicability.